

SUPPORTING INFORMATION

**The effect of the disposition of coordinated oxygen atoms on the
magnitude of the energy barrier for magnetization reversal in a family
of linear trinuclear Zn-Dy-Zn complexes with square-antiprism DyO_8
coordination sphere**

Itziar Oyarzabal, Antonio Rodríguez-Diéguéz, Montserrat Barquin, José M. Seco and
Enrique Colacio

Table S.1.- Crystallographic data for complexes **1-6**.

Complex	1	2	3	4	5	6
Formula	C ₄₁ H ₄₄ N ₅ O ₁₂ Cl ₂ Br ₄ Zn ₂ Dy	C ₄₂ H ₅₂ N ₄ O ₁₂ Br ₉ Zn ₃ Dy	C ₄₃ H ₅₂ N ₅ O ₁₄ Br ₆ Zn ₂ Dy	C ₄₁ H ₄₄ N ₄ O ₁₂ Br ₄ I ₃ Zn ₂ Dy	C ₄₃ H ₅₂ N ₅ O ₁₄ Br ₄ I ₂ Zn ₂ Dy	C ₄₁ H ₄₆ N ₁₁ O ₁₃ Br ₄ Zn ₂ Dy
M _r	1482.59	1882.67	1635.59	1778.38	1729.57	1513.77
Crystal system	Triclinic	Monoclinic	Monoclinic	Monoclinic	Monoclinic	Triclinic
Space group (no.)	P-1 (2)	P21/n (14)	P21/c (14)	P21/c (14)	P21/c (14)	P-1 (2)
a (Å)	11.820(2)	14.6756(11)	14.6274(3)	14.9193(3)	14.7655(3)	13.6069(7)
b (Å)	12.875(2)	13.0146(9)	27.3664(5)	25.4989(3)	27.0577(4)	13.8358(9)
c (Å)	15.948(3)	30.607(2)	14.7306(4)	15.6761(3)	15.1740(3)	15.9283(7)
α (°)	98.179(3)	90	90	90	90	99.998(5)
β (°)	94.615(3)	93.627(2)	115.170(3)	116.881(2)	115.552(2)	108.143(5)
γ (°)	91.774(3)	90	90	90	90	106.028(5)
V(Å ³)	2392.2(7)	5834.1(7)	5336.8(2)	5319.21(18)	5469.39(19)	2625.9(3)
Z	2	4	4	4	4	2
D _c (g cm ⁻³)	2.058	2.143	2.036	2.221	2.100	1.851
m(MoK _a) (mm ⁻¹)	6.058	8.705	6.836	7.090	6.338	5.421
T (K)	100(2)	100(2)	100(2)	100(2)	100(2)	100(2)
Observed reflections	10772 (9031)	14924 (12409)	11840 (8854)	12209 (10629)	12541 (10581)	11643 (7756)
R _{int}	0.0442	0.0664	0.0564	0.0325	0.0331	0.0610
Parameters	610	647	650	609	627	590
GOF	1.009	1.065	1.026	1.053	1.051	0.951
R ₁ ^{a,b}	0.0444 (0.0352)	0.0698 (0.0551)	0.0811 (0.0533)	0.0545 (0.0460)	0.0558 (0.0441)	0.0959 (0.0587)
wR ₂ ^c	0.0832 (0.0785)	0.1357 (0.1254)	0.1235 (0.1085)	0.1225 (0.1177)	0.1083 (0.1022)	0.1254 (0.1114)
Largest difference in peak and hole (e Å ⁻³)	1.599 and -0.735	3.740 and -3.322	2.139 and -2.347	2.041 and -4.678	5.120 and -1.786	1.858 and -1.692

^a R₁ = S||F_o| - |F_c||/S|F_o|. ^b Values in parentheses for reflections with I > 2s(I). ^c wR₂ = {S[w(F_o² - F_c²)²] / S[w(F_o²)²]}^{1/2}

Table S.2.- Selected bond lengths (\AA) and angles ($^\circ$) for complexes **1-6**.

Complex	1	2	3	4	5	6
Dy(1)…Zn(1)	3.553(1)	3.573(1)	3.569(1)	3.568(1)	3.571(1)	3.568(1)
Dy(1)…Zn(2)	3.534(1)	3.572(1)	3.562(1)	3.546(1)	3.564(1)	3.591(1)
Dy(1)-O(1A)	2.385(3)	2.393(4)	2.385(4)	2.378(5)	2.389(5)	2.364(5)
Dy(1)-O(2A)	2.290(3)	2.335(4)	2.321(5)	2.329(5)	2.243(4)	2.350(5)
Dy(1)-O(3A)	2.321(3)	2.235(4)	2.239(4)	2.246(5)	2.333(4)	2.263(4)
Dy(1)-O(4A)	2.392(3)	2.448(4)	2.393(5)	2.414(5)	2.390(4)	2.454(5)
Dy(1)-O(1B)	2.388(3)	2.405(4)	2.408(5)	2.387(5)	2.403(4)	2.397(5)
Dy(1)-O(2B)	2.303(3)	2.330(4)	2.277(5)	2.322(5)	2.310(4)	2.340(4)
Dy(1)-O(3B)	2.317(3)	2.251(4)	2.316(5)	2.264(5)	2.279(4)	2.261(5)
Dy(1)-O(4B)	2.374(3)	2.426(4)	2.401(4)	2.416(5)	2.405(5)	2.412(5)
Zn(1)-N(1A)	2.123(3)	2.173(5)	2.151(6)	2.169(6)	2.141(5)	2.133(6)
Zn(1)-N(2A)	2.145(3)	2.102(5)	2.145(6)	2.124(6)	2.158(5)	2.111(6)
Zn(1)-O(2A)	2.137(3)	2.055(4)	2.081(4)	2.098(5)	2.101(4)	2.044(5)
Zn(1)-O(3A)	2.066(3)	2.148(4)	2.078(5)	2.100(5)	2.078(4)	2.125(5)
Zn(1)-X(1A)	2.214(1)	2.356(1)	2.360(1)	2.556(1)	2.5421(8)	1.992(6)

Table S.2.- Continuation.

Complex	1	2	3	4	5	6
Zn(2)-N(1B)	2.138(4)	2.163(5)	2.098(5)	2.182(6)	2.188(5)	2.154(6)
Zn(2)-N(2B)	2.153(4)	2.122(5)	2.186(6)	2.115(6)	2.105(5)	2.114(6)
Zn(2)-O(2B)	2.087(3)	2.057(4)	2.166(5)	2.058(5)	2.043(4)	2.058(4)
Zn(2)-O(3B)	2.101(3)	2.142(4)	2.047(5)	2.156(5)	2.171(4)	2.147(5)
Zn(2)-X(1B)	2.218(1)	2.355(1)	2.372(1)	2.570(1)	2.559(1)	1.971(7)
Zn(3)-Br(1C)		2.378(2)				
Zn(3)-Br(2C)		2.385(2)				
Zn(3)-Br(3C)		2.350(2)				
Zn(3)-O(4M)		2.009(8)				
Dy(1)-O(2A)-Zn(1)	106.73(11)	108.82(17)	108.23(19)	107.29(19)	110.55(17)	108.4(2)
Dy(1)-O(3A)-Zn(1)	108.08(11)	109.20(17)	111.5(2)	110.3(2)	107.97(17)	108.8(2)
Dy(1)-O(2B)-Zn(2)	107.16(11)	108.87(17)	106.59(19)	107.99(19)	109.73(18)	109.3(2)
Dy(1)-O(3B)-Zn(2)	106.18(11)	108.79(17)	109.3(2)	106.68(19)	106.38(17)	109.1(2)
O(2A)-Zn(1)-O(3A)	75.96(10)	74.23(15)	73.79(18)	74.62(18)	74.29(15)	75.56(18)
O(2B)-Zn(2)-O(3B)	76.47(10)	74.30(15)	75.46(18)	75.69(18)	75.23(16)	74.25(18)
O(2A)-Dy(1)-O(3A)	68.26(9)	67.41(14)	66.36(16)	67.55(17)	66.91(14)	67.24(16)
O(2B)-Dy(1)-O(3B)	68.28(9)	67.22(14)	68.32(16)	68.66(16)	68.24(14)	66.97(17)
Zn(1)-Dy(1)-Zn(2)	105.94(2)	143.743(17)	146.77(2)	146.95(2)	146.249(18)	141.56(2)

Table S.3.- Shape measures for Dy(III) coordination environments in complexes **1-6**.

Complex	SAPR-8	TDD-8	JBTPR-8	BTPR-8	JSD-8
1	0.504	2.590	3.078	2.405	5.492
2	0.804	2.329	3.435	2.982	5.837
3	0.544	2.367	2.974	2.454	5.296
4	0.458	2.227	2.892	2.454	5.317
5	0.510	2.377	2.957	2.450	5.384
6	1.060	2.160	3.574	3.142	5.868

* SAPR-8: square antiprism (D_{4d}); TDD-8: triangular dodecahedron (D_{2d}); JBTPR-8: Biaugmented trigonal prism J50 (C_{2v}); BTPR-8: biaugmented trigonal prism (C_{2v}); JSD-8: Snub diphenoïd J84 (D_{2d}).

*Shape measures relative to other reference polyhedron are significantly larger.

Table S.4- Shape measures for Zn(II) coordination environments in complexes **1-6**.

Complex	PP-5	vOC-5	TBPY-5	SPY-5	JTBPY-5
1-Zn1	32.663	3.344	4.331	0.572	7.493
1-Zn2	32.571	3.700	4.595	0.687	8.146
2-Zn1	33.426	4.677	3.833	1.223	7.206
2-Zn2	33.651	4.559	4.166	1.118	7.675
3-Zn1	32.887	4.792	4.126	1.242	8.049
3-Zn2	33.765	4.569	4.677	1.017	8.041
4-Zn1	33.807	5.574	4.321	1.714	8.478
4-Zn2	33.941	5.627	4.732	1.662	8.603
5-Zn1	34.333	5.532	4.383	1.650	8.560
5-Zn2	34.123	5.478	5.135	1.504	8.914
6-Zn1	31.976	2.884	3.369	0.696	5.913
6-Zn2	31.454	2.979	3.609	0.730	6.058

*PP-5: pentagon (D_{5h}); vOC-5: vacant octahedron (C_{4v}); TBPY-5: trigonal bipyramide (D_{3h}); SPY-5: square pyramid (C_{4v}); JTBPY-5: Johnson trigonal bipyramide (D_{3h}).

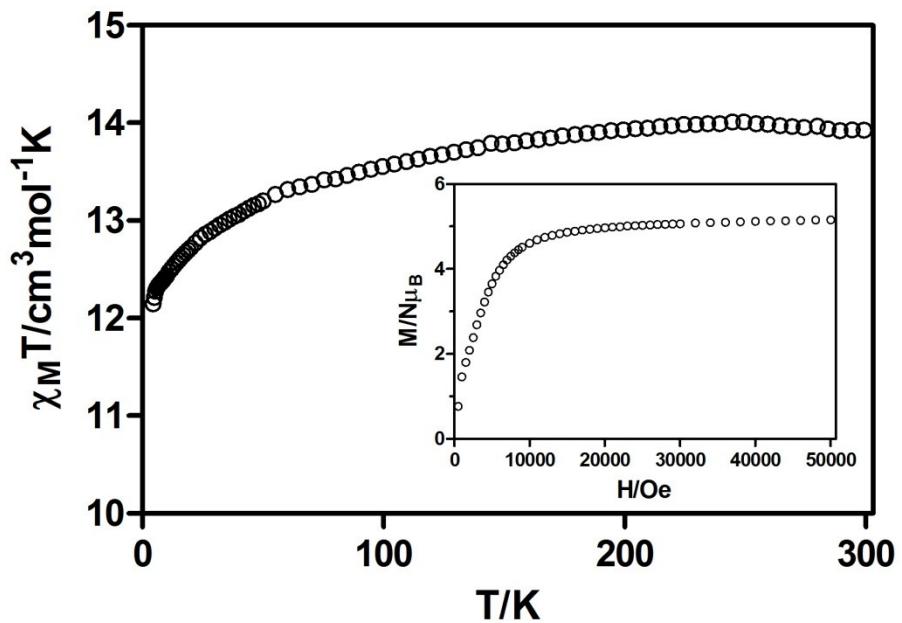


Figure S.1.- Temperature dependence of $\chi_M T$ for **1**. Inset: Field dependence of the molar magnetization for **1**.

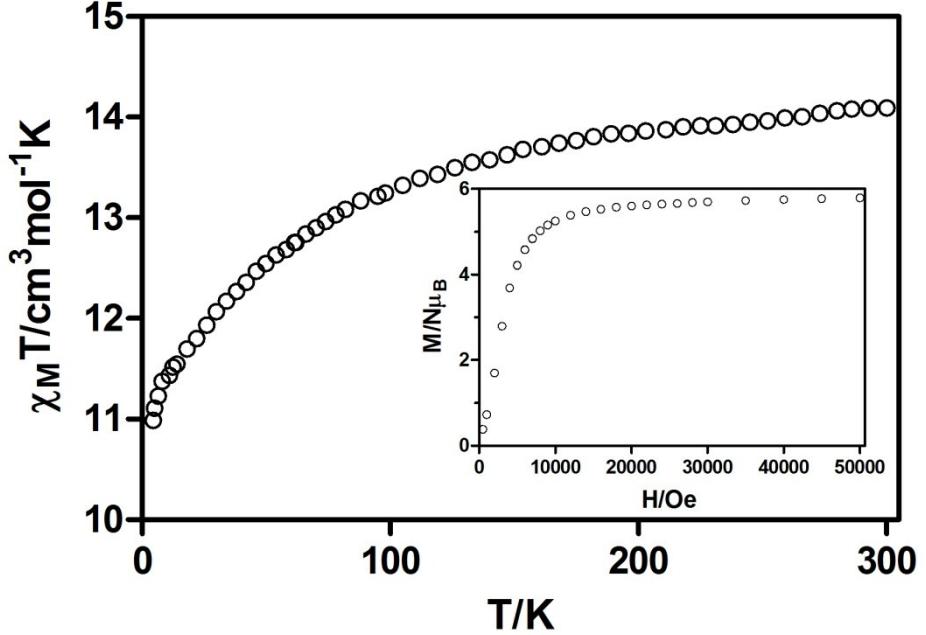


Figure S.2.- Temperature dependence of $\chi_M T$ for **2**. Inset: Field dependence of the molar magnetization for **2**.

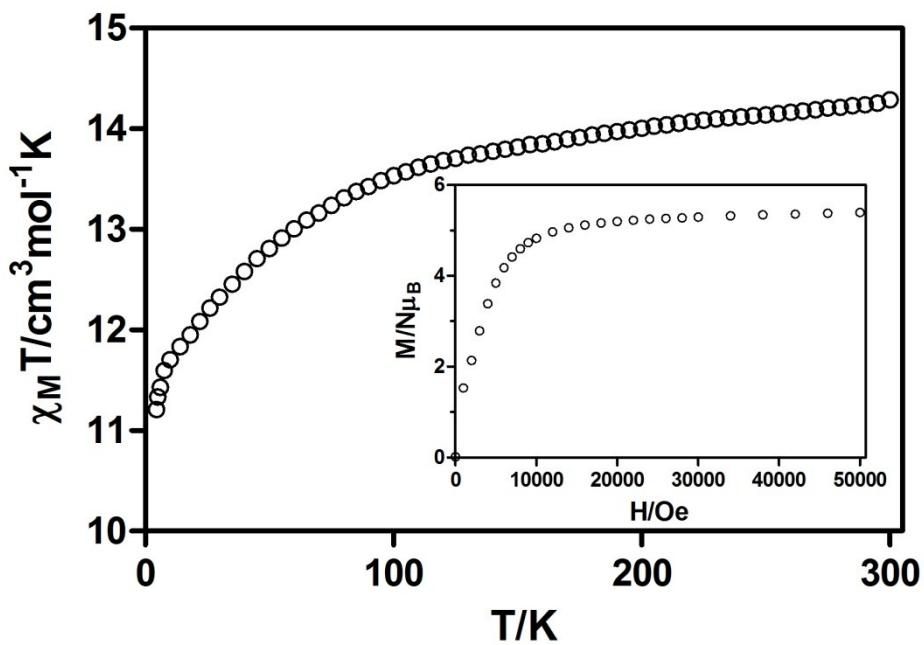


Figure S.3.- Temperature dependence of $\chi_M T$ for **3**. Inset: Field dependence of the molar magnetization for **3**.

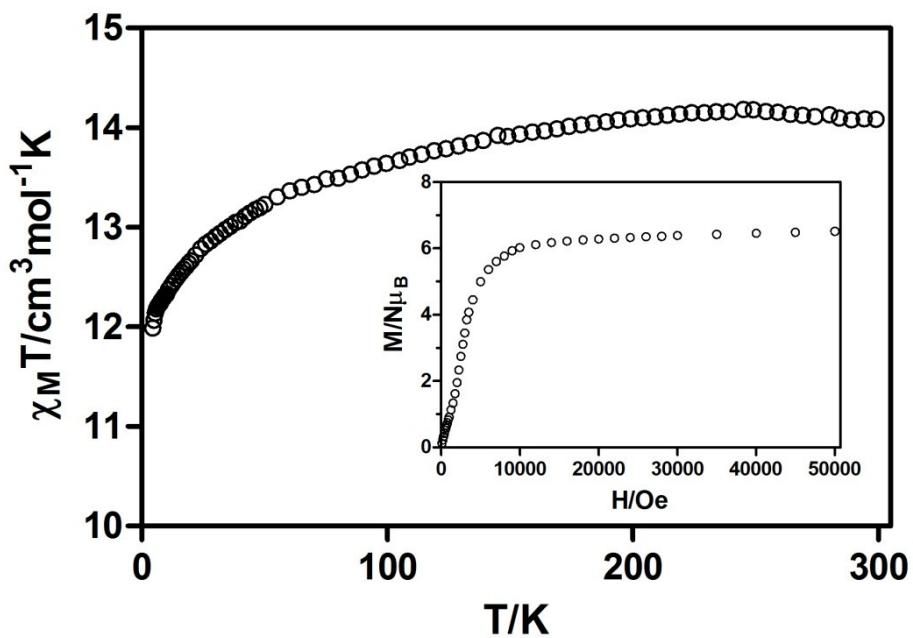


Figure S.4.- Temperature dependence of $\chi_M T$ for **4**. Inset: Field dependence of the molar magnetization for **4**.

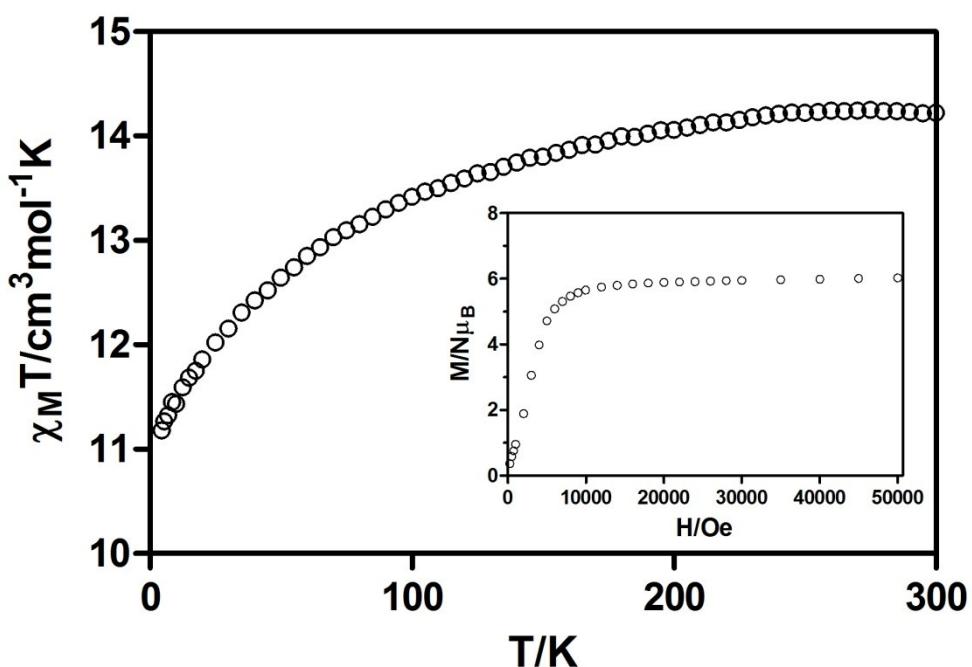


Figure S.5.- Temperature dependence of $\chi_M T$ for **5**. Inset: Field dependence of the molar magnetization for **5**.

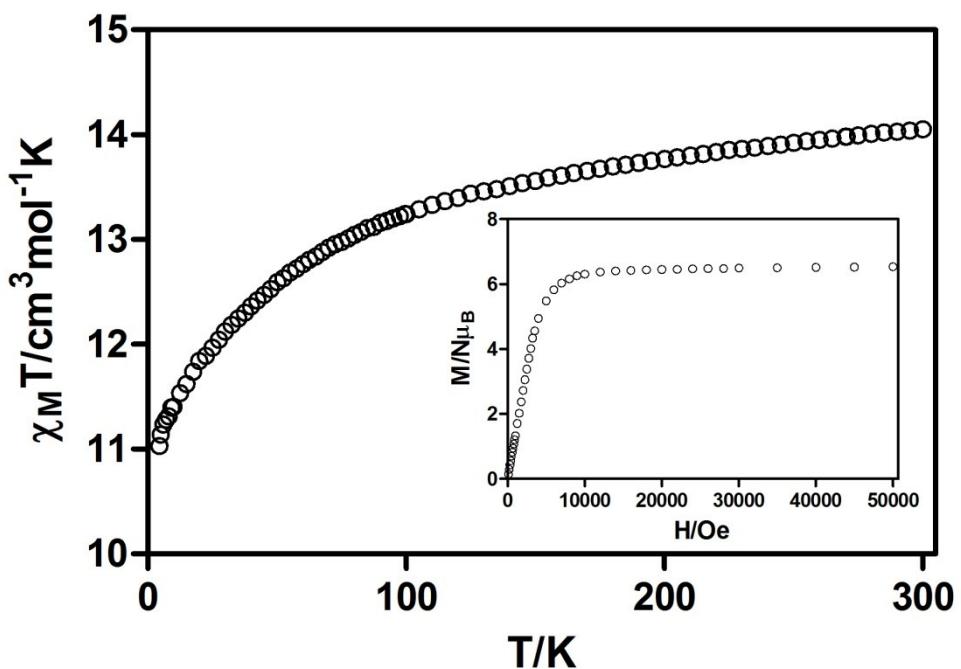


Figure S.6.- Temperature dependence of $\chi_M T$ for **6**. Inset: Field dependence of the molar magnetization for **6**.

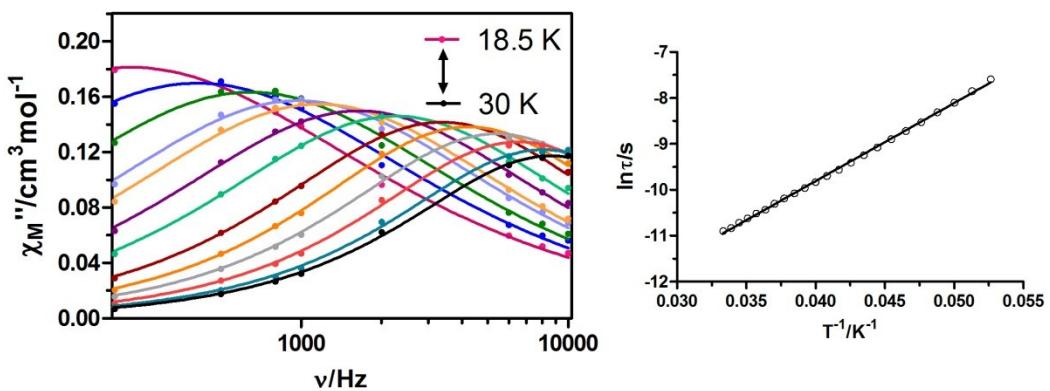
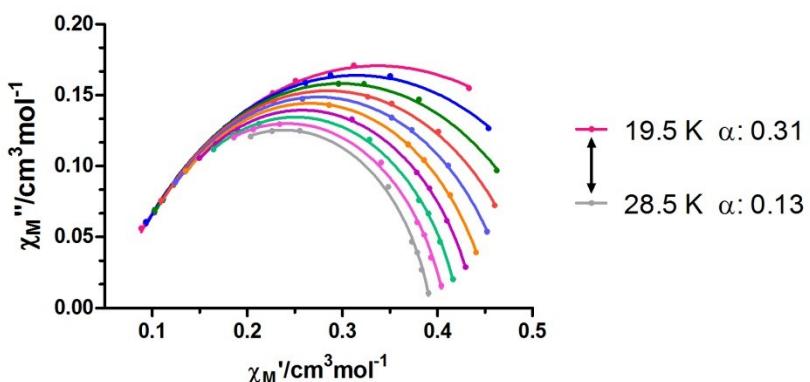
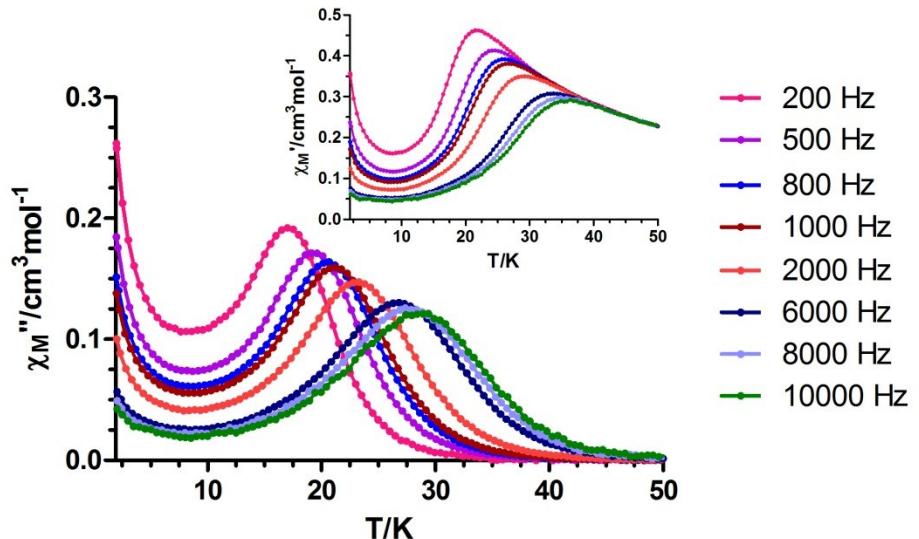


Figure S.7.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **1** under zero applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **1** (black line).

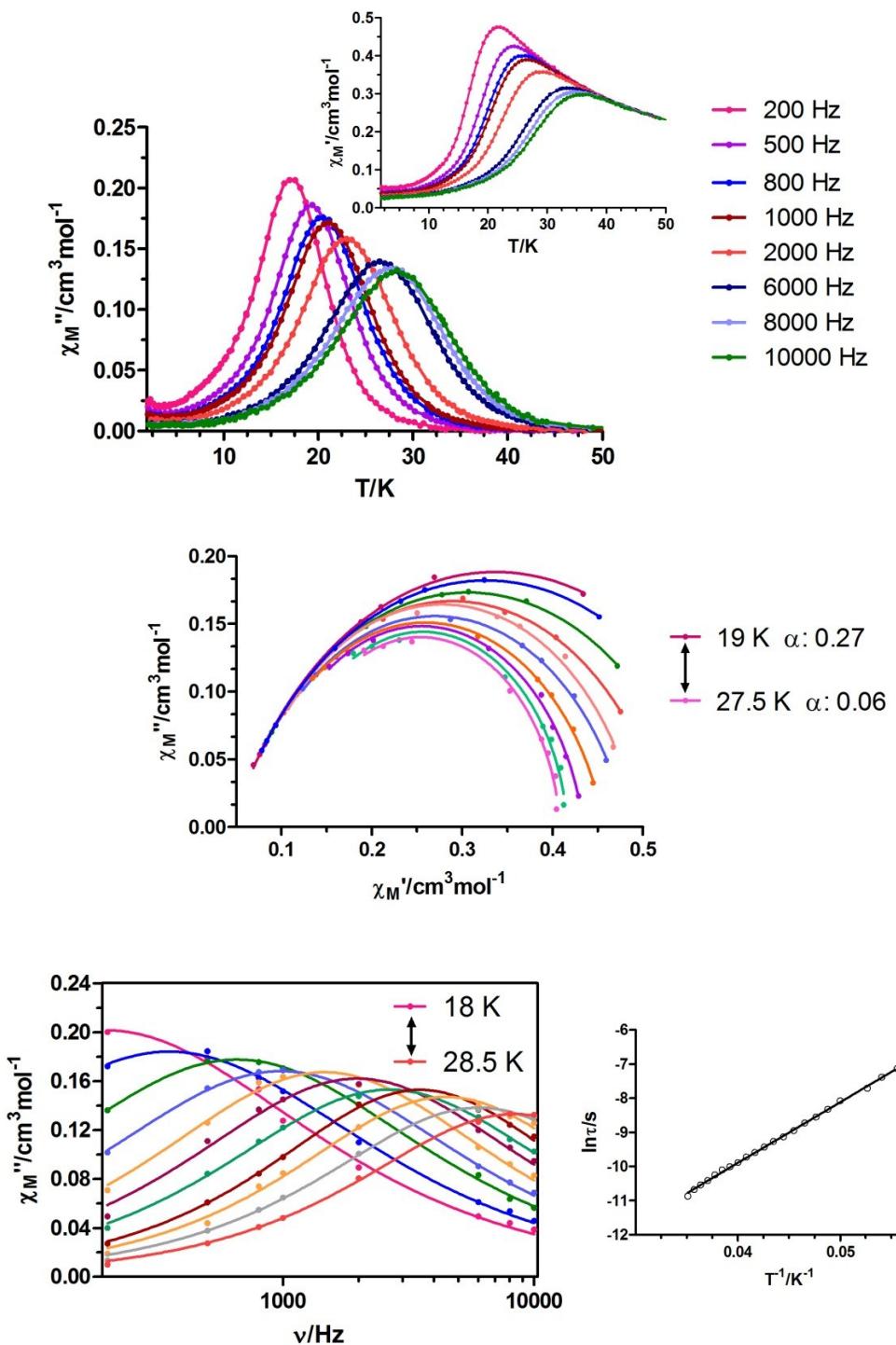


Figure S.8.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **1** under 1000 Oe applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **1** (black line).

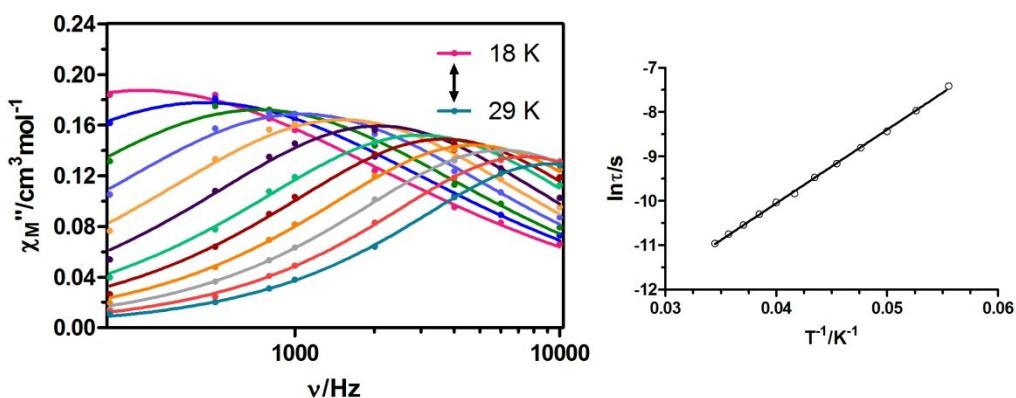
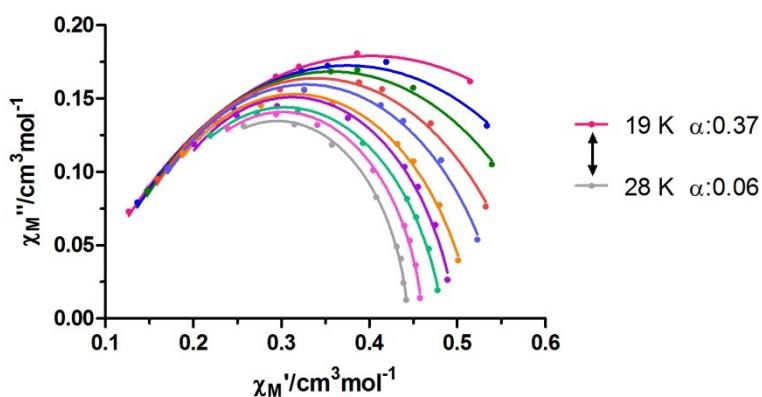
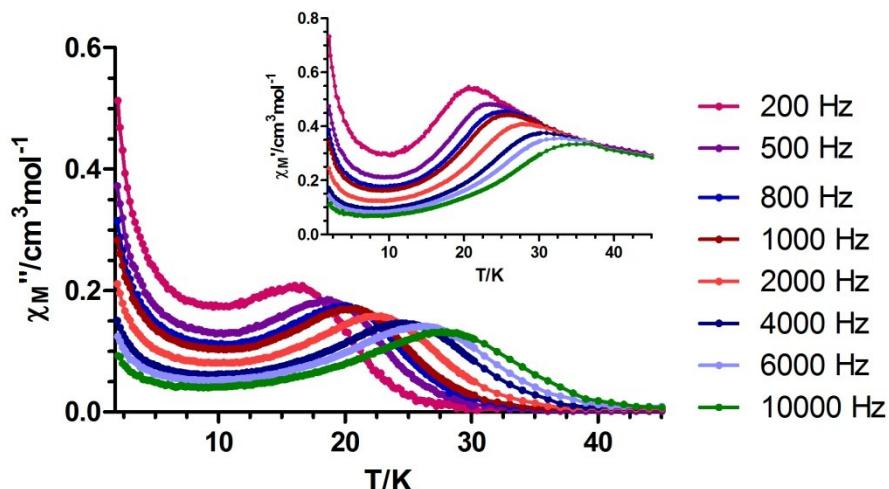


Figure S.9.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **2** under zero applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **2** (black line).

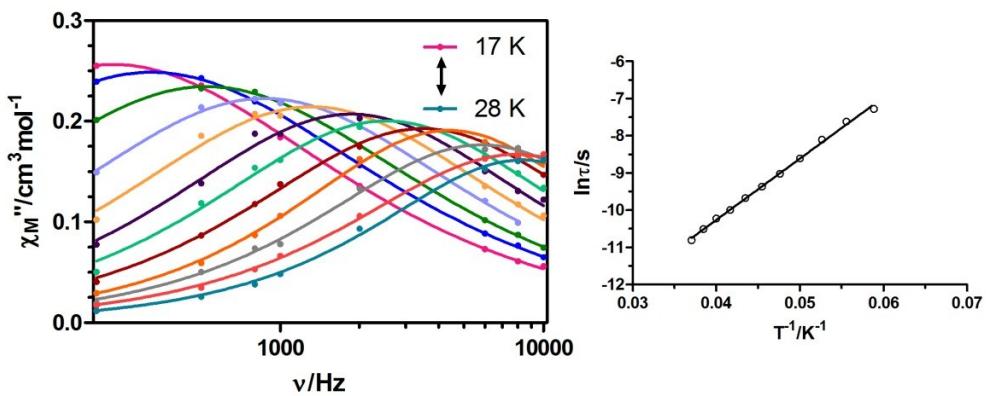
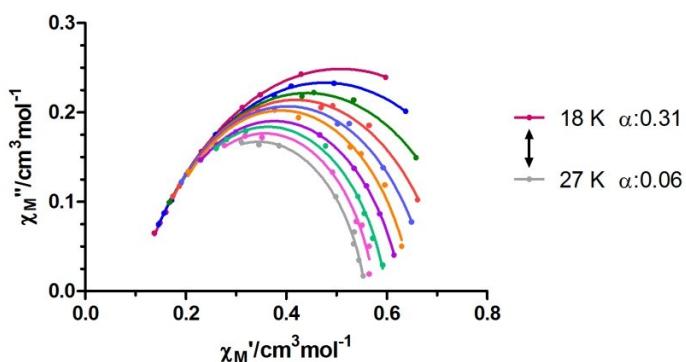
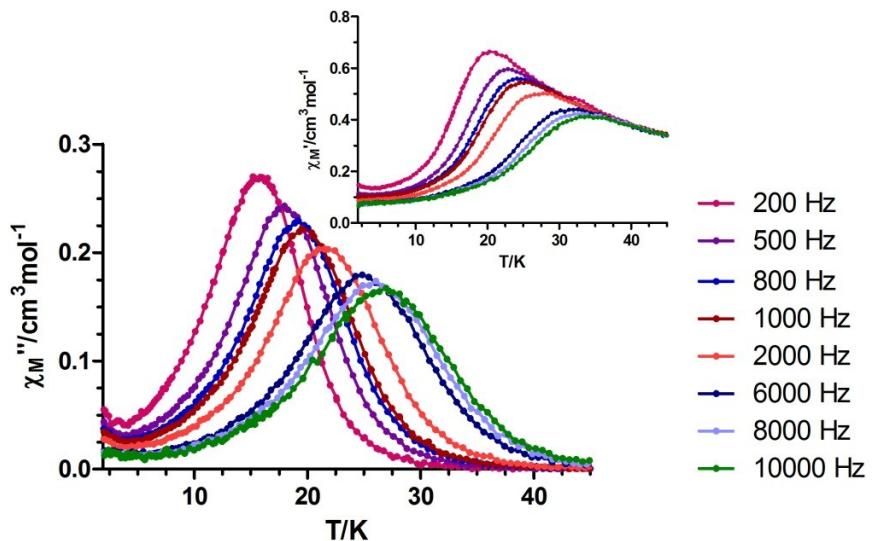


Figure S.10.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **2** under 1000 Oe applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **2** (black line).

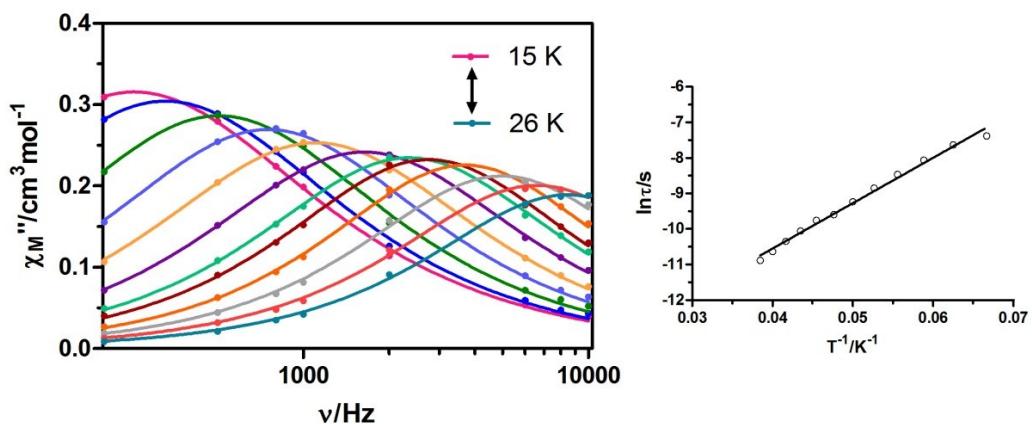
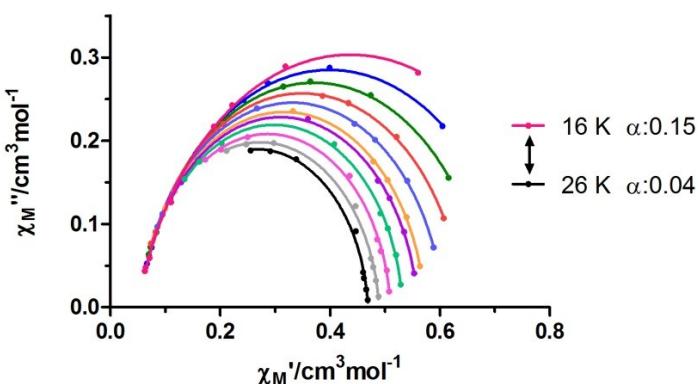
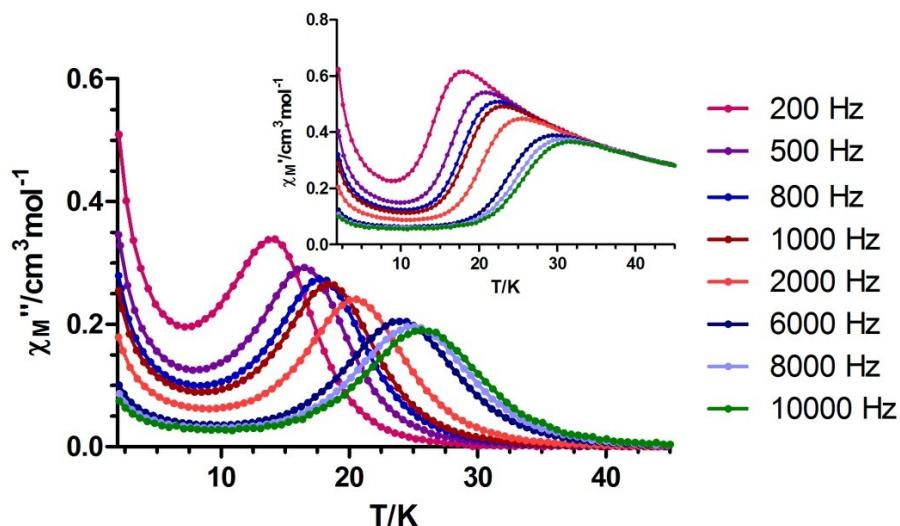


Figure S.11.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **3** under zero applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **3** (black line).

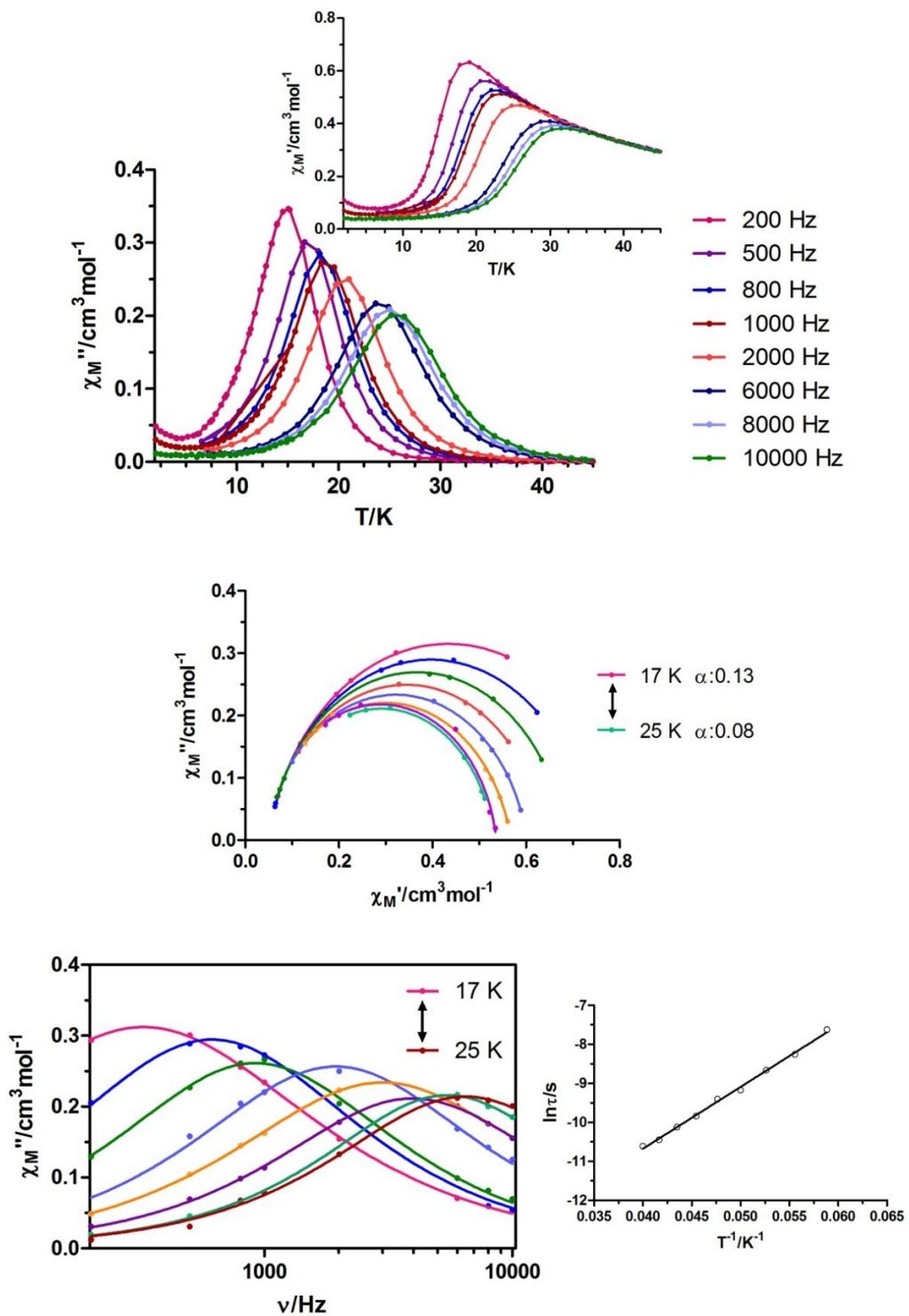


Figure S.12.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **3** under 1000 Oe applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **3** (black line).

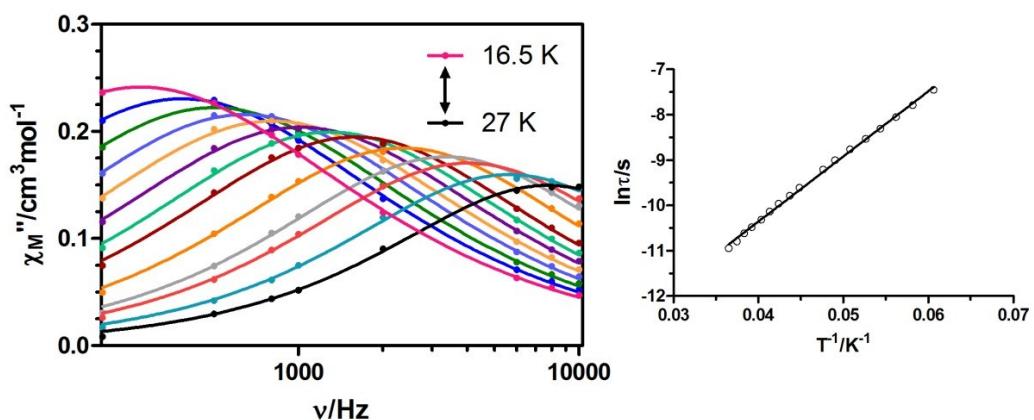
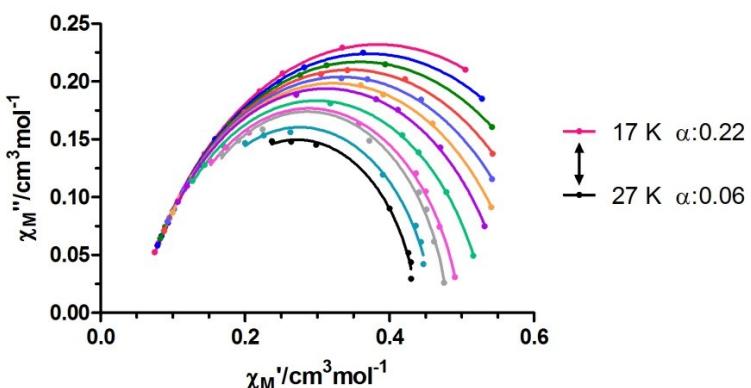
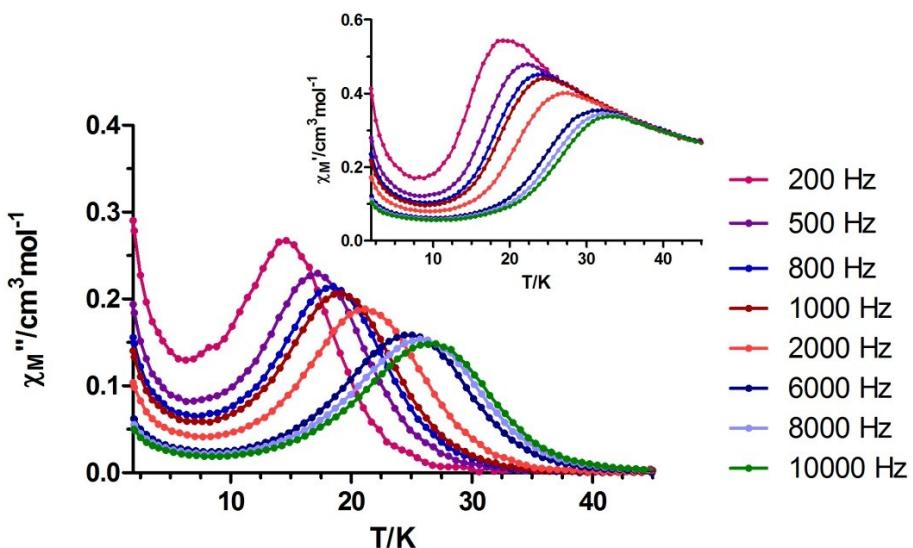


Figure S.13.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex 4 under zero applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of 4 (black line).

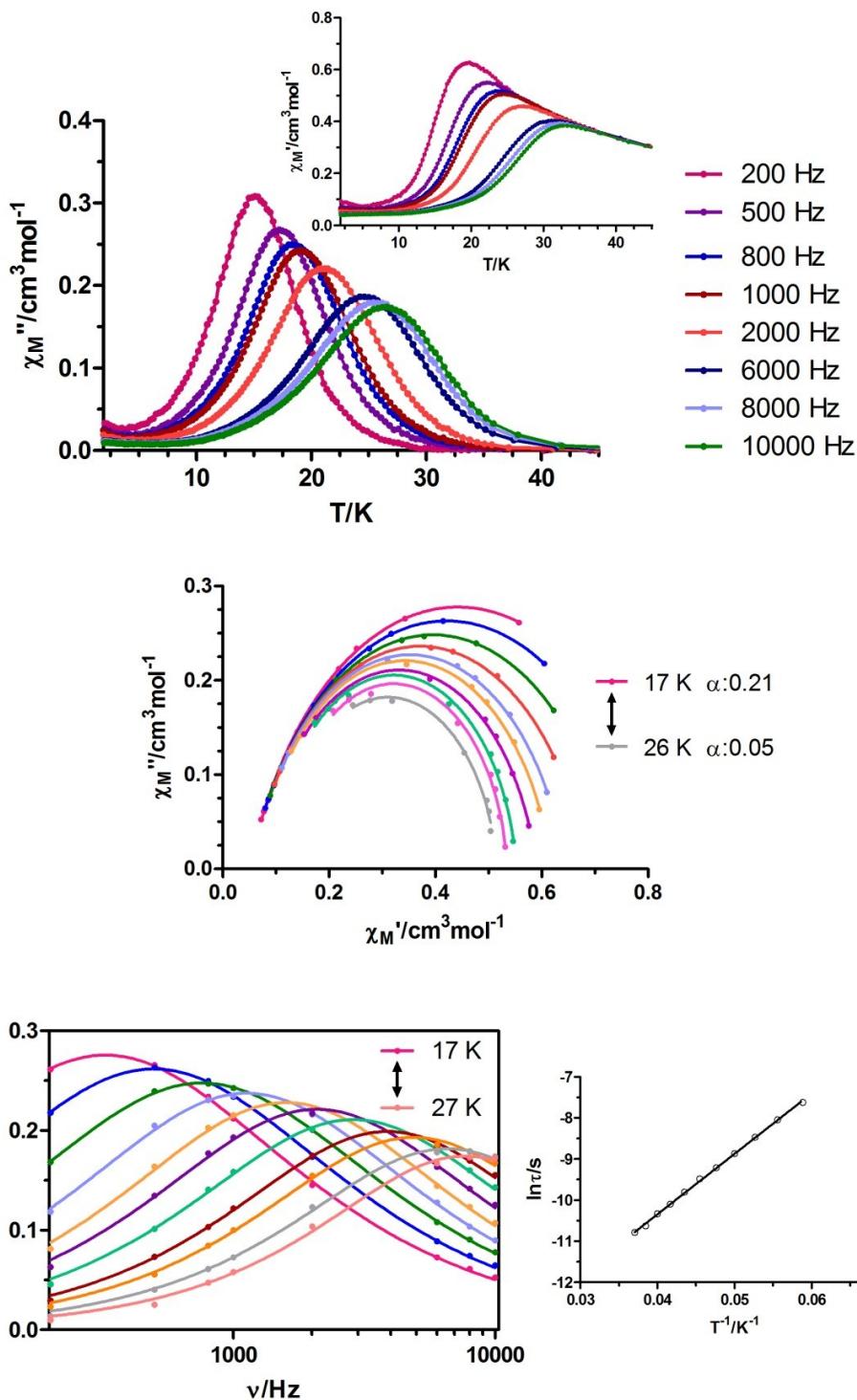


Figure S.14.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex 4 under 1000 Oe applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of 4 (black line).

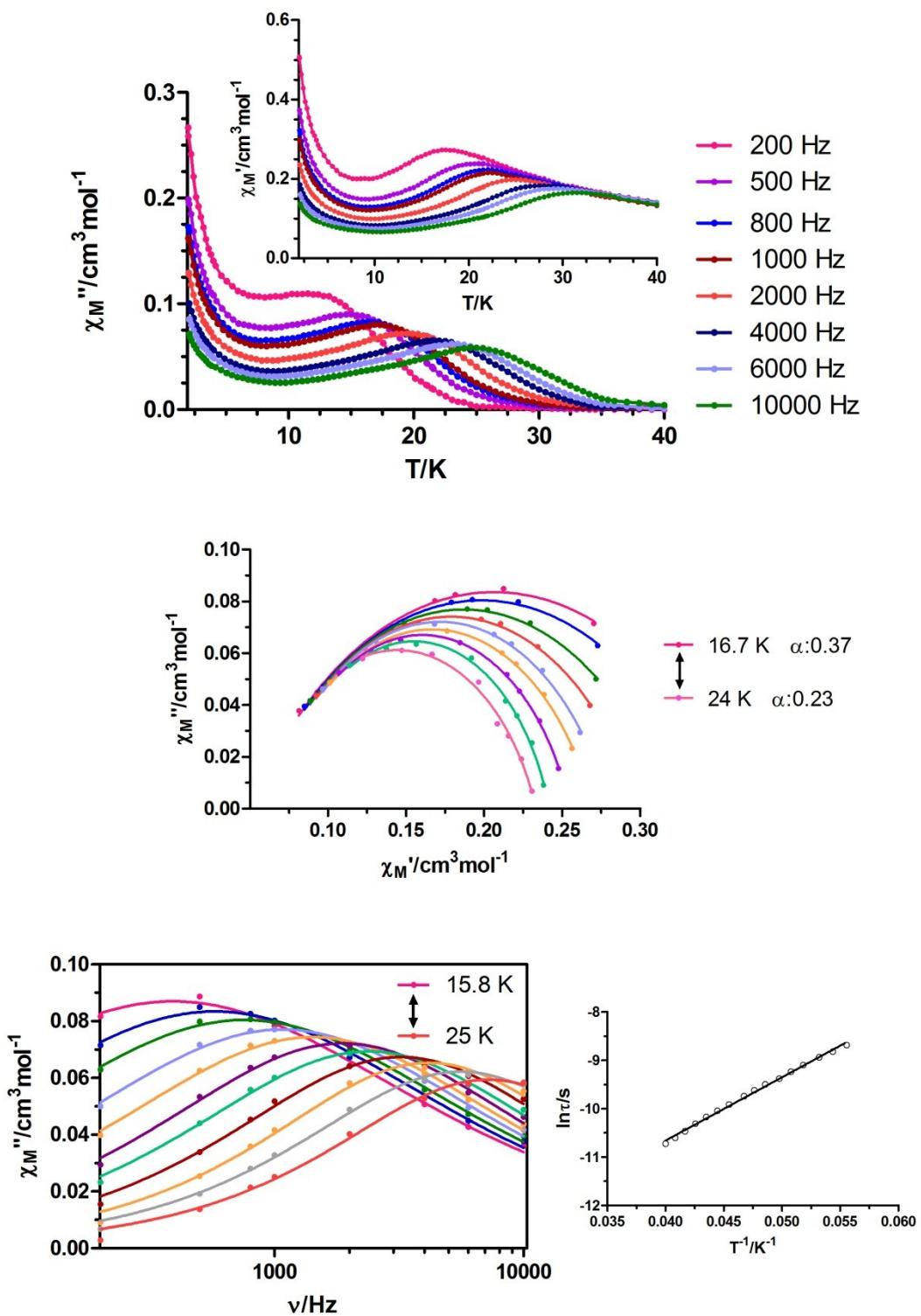


Figure S.15.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **5** under zero applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **5** (black line).

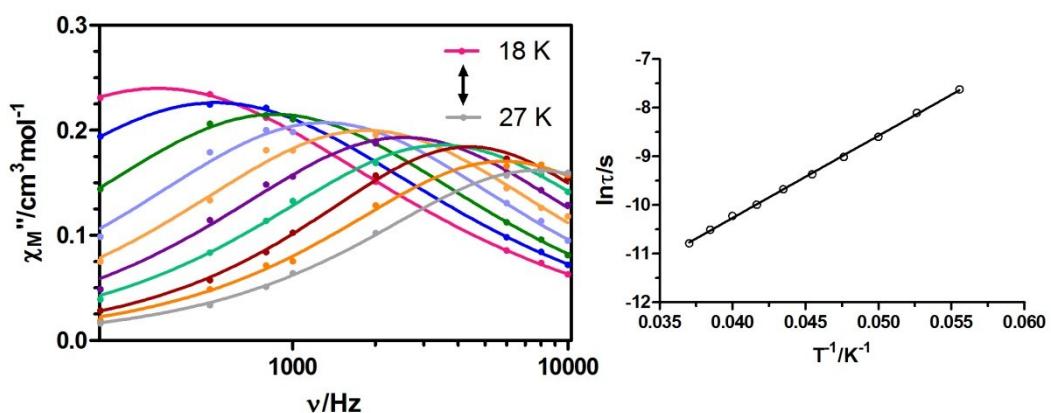
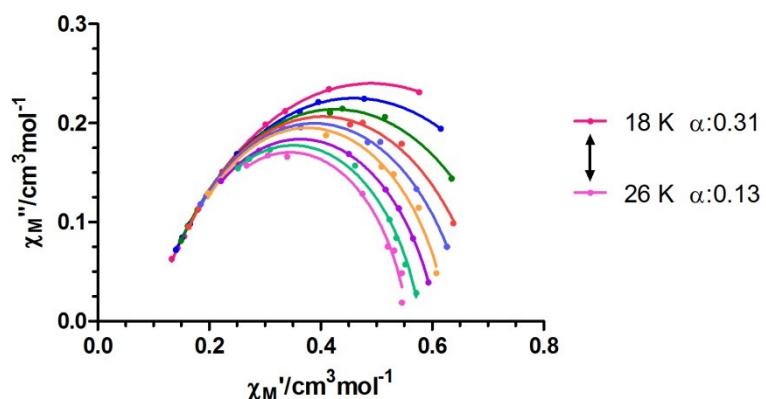
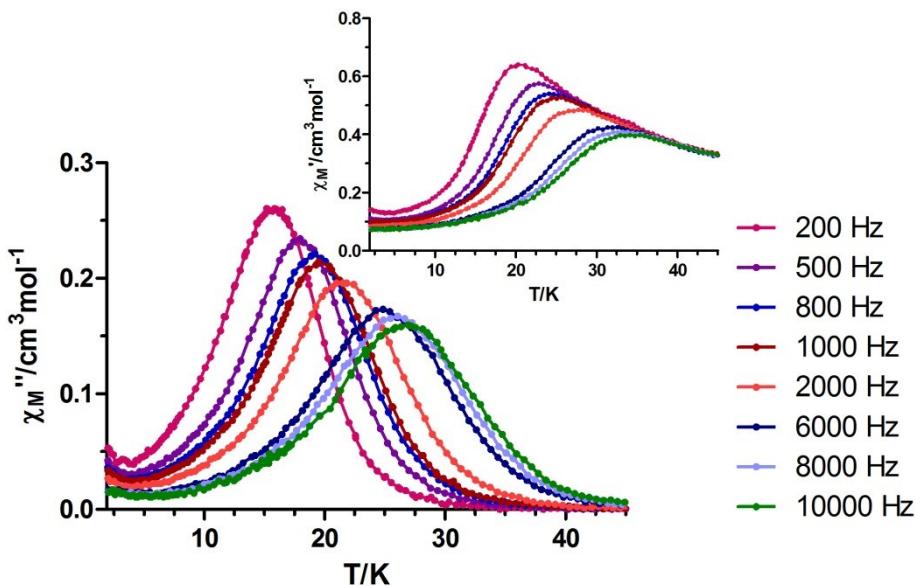


Figure S.16.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **5** under 1000 Oe applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **5** (black line).

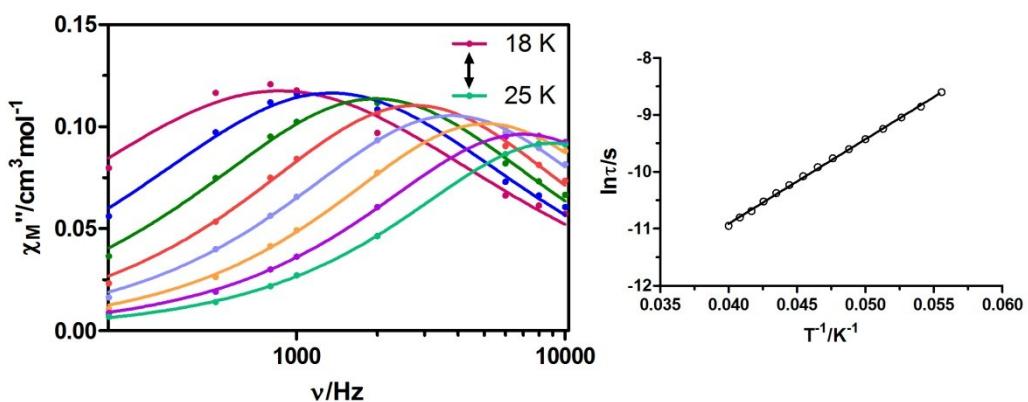
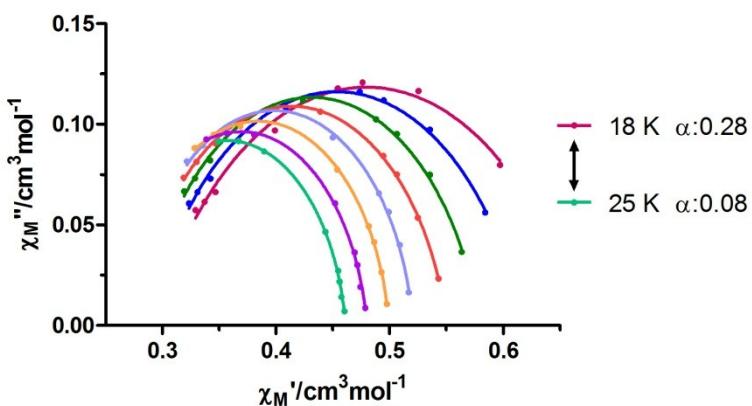
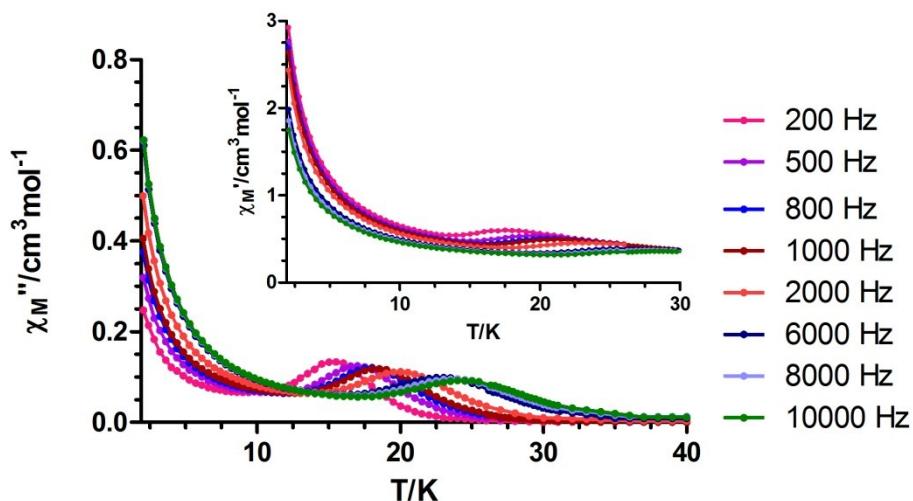


Figure S.17.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **6** under zero applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **6** (black line).

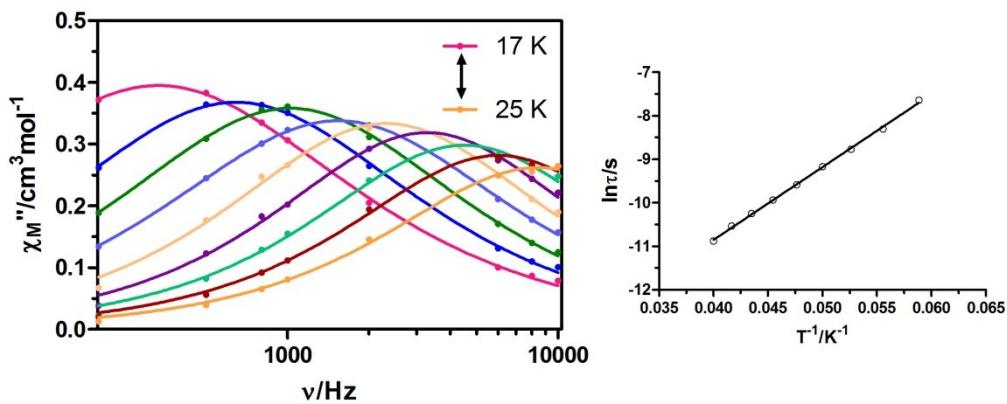
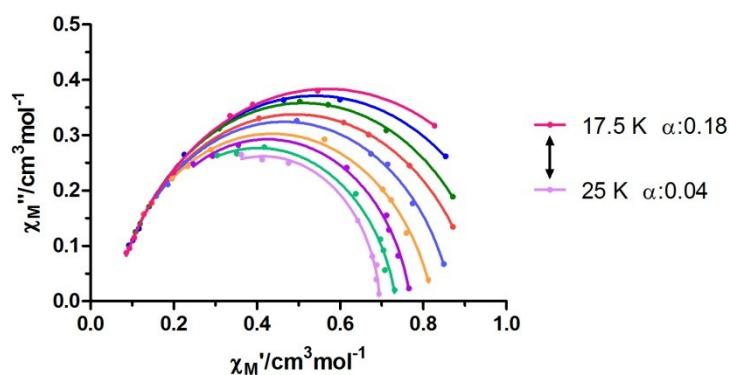
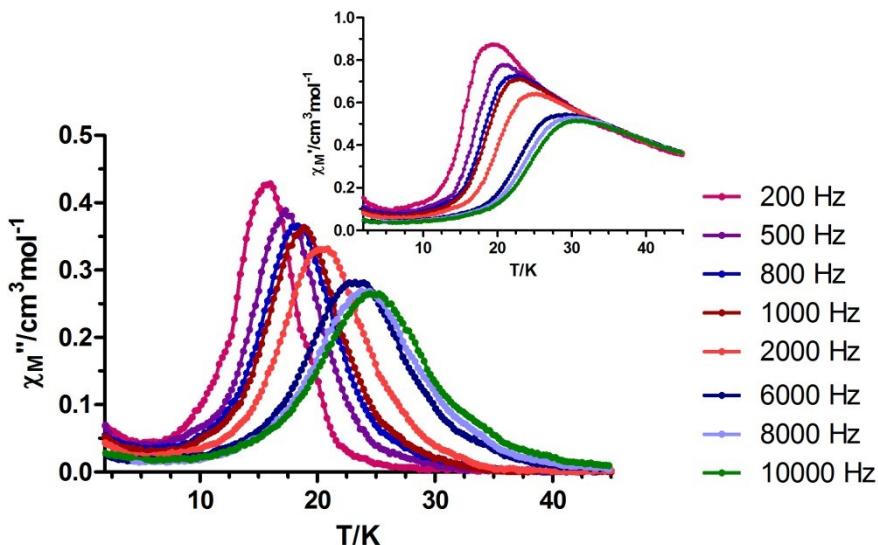


Figure S.18.- Top: temperature dependence of in-phase χ_M' (inset) and out-of phase χ_M'' components of the *alternating current* susceptibility for complex **6** under 1000 Oe applied external field. Medium: Cole-Cole plot. Bottom left: variable-temperature frequency dependence of the χ_M'' signal. Bottom right: Arrhenius plots for the relaxation of **6** (black line).

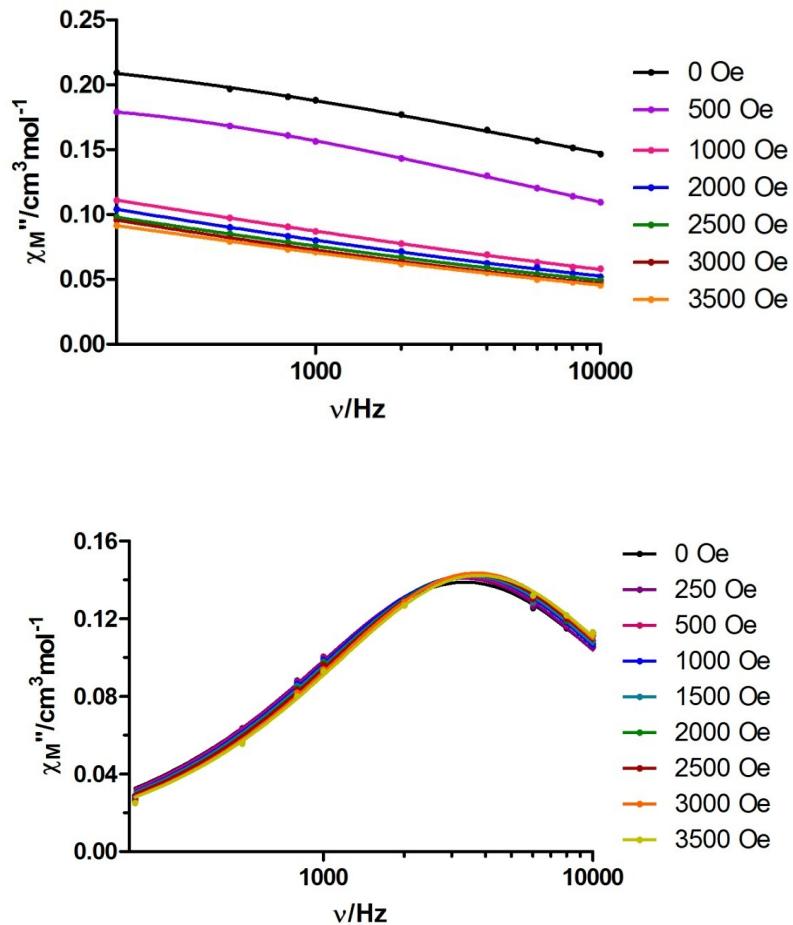


Figure S.19.- Field dependence of out-of-phase signals vs. frequency at 4 K (top) and 25 K (bottom) for **1**.

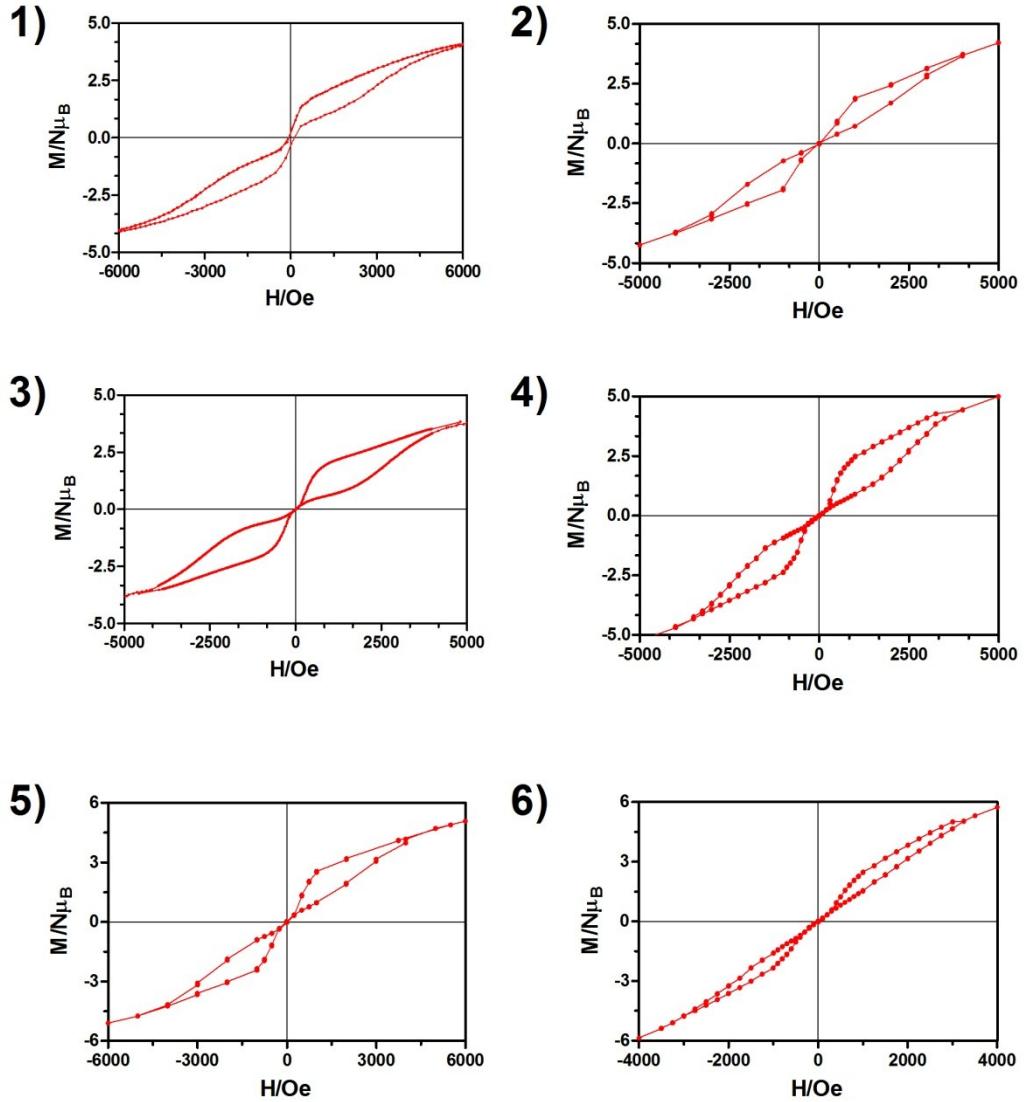


Figure S.20.- Magnetic Hysteresis loops for 1-6. Red solid lines represent a guide to the eye.

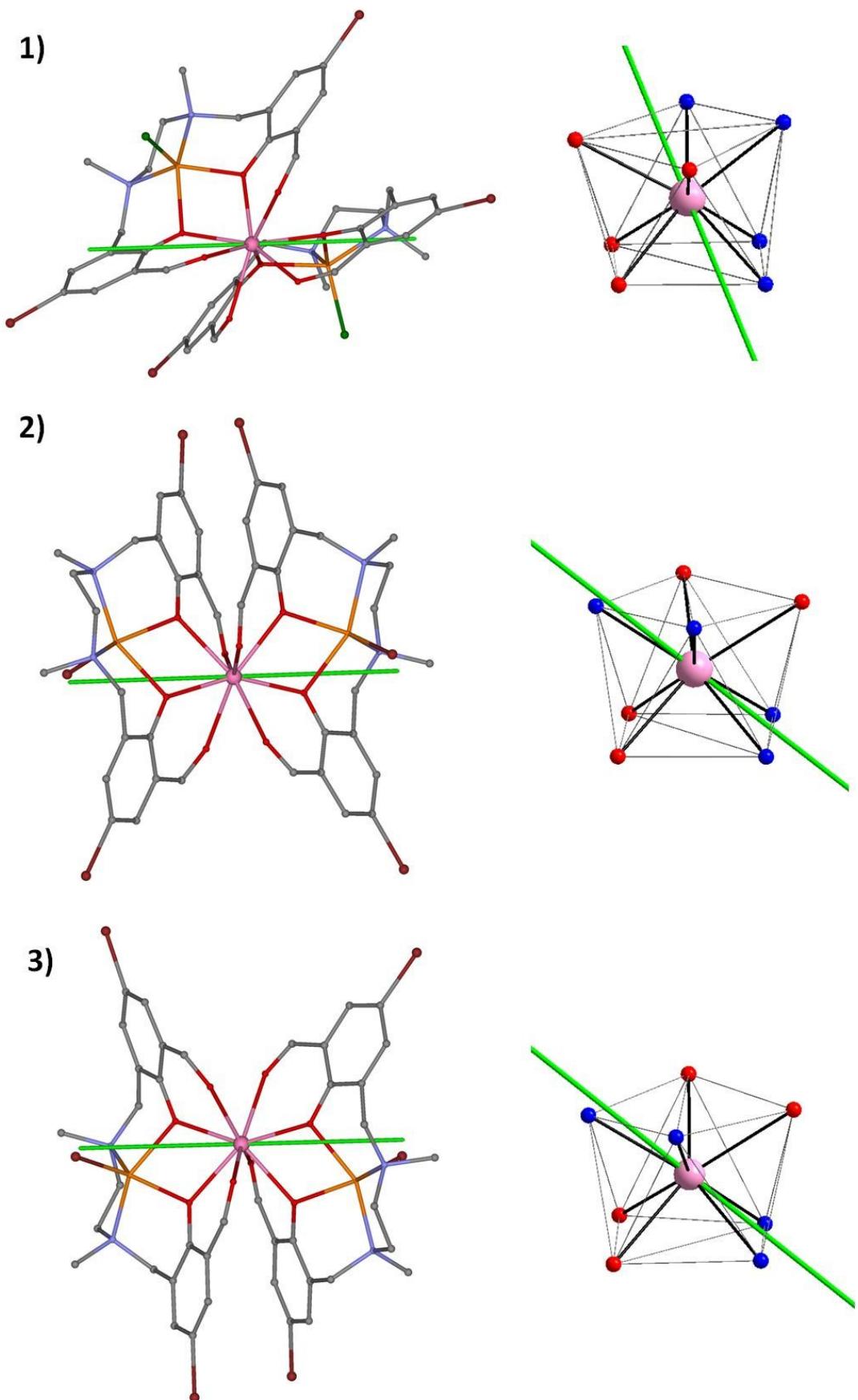


Figure S.21.- Anisotropy axis for the Dy(III) ion (green line) for **1-6** and $[\text{ZnCl}(\mu\text{-L})\text{Dy}(\mu\text{-L})\text{ClZn}][\text{ZnCl}_3(\text{CH}_3\text{OH})]$.

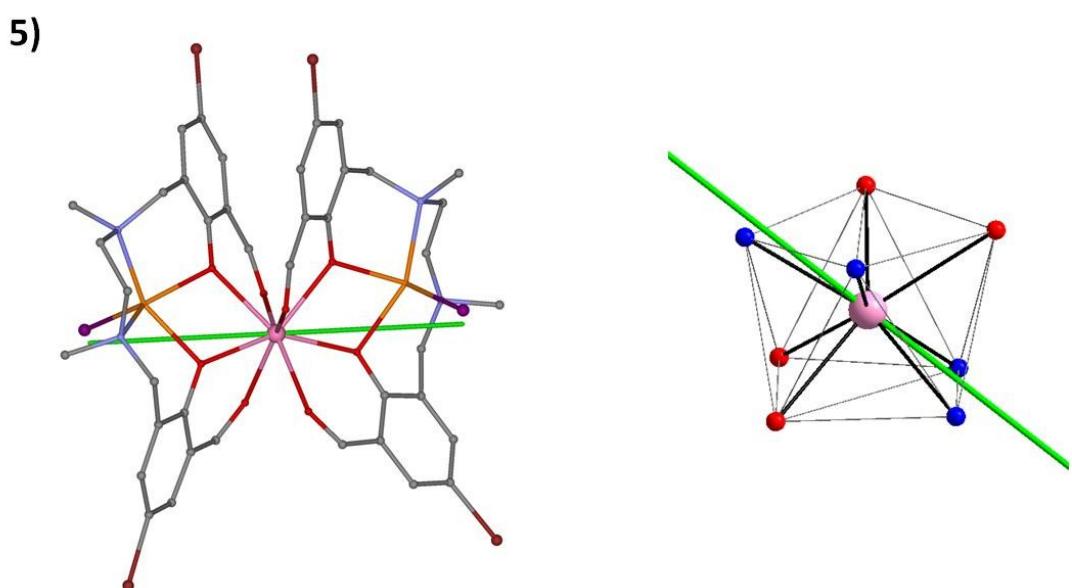
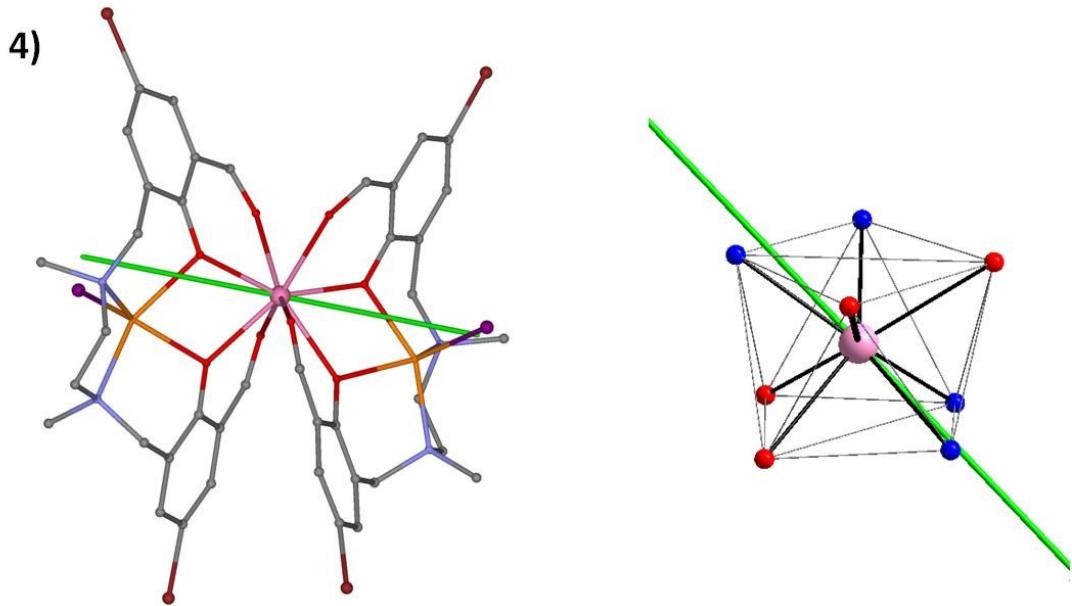


Figure S.21.- Continuation.

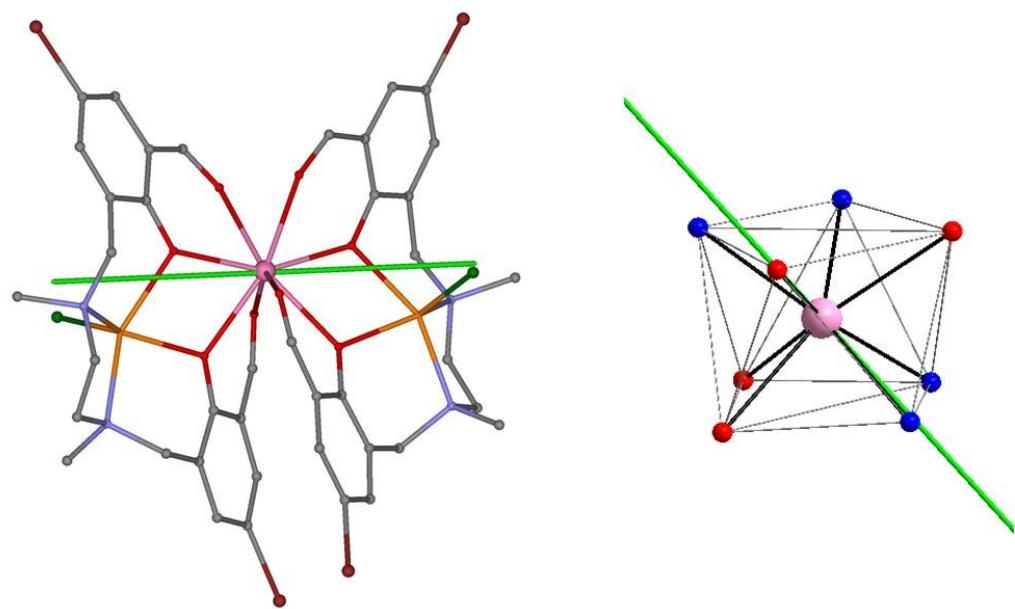
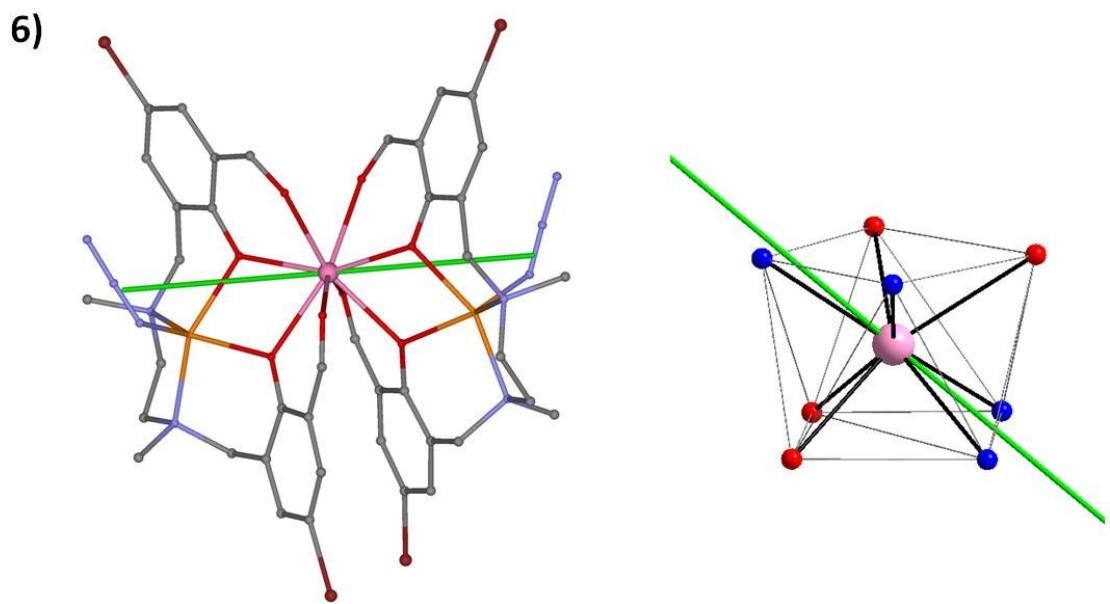


Figure S.21.- Continuation.

Table S.5- Summary of the Zn(II) and Dy(III) based SIMs.

Complex	Closest ideal geometry by SHAPE	CshM value	U_{eff} (K)	T_B (K) Scan rate (Ts ⁻¹)	Ref
ZnDy	[ZnDy(L1)(sal)Br(NO ₃)(MeOH)]	MFF-9	1.154	333 94, 336 (1000)	- [1]
	[Zn(NO ₃) (L2) Dy(NO ₃) ₂ (H ₂ O)]	TCTPR-9	2.530	39.41 (900)	- [2]
	[DyZn(L3)(OAc) ₂ (NO ₃)] <cdot;ch<sub>3OH</cdot;ch<sub>	MFF-9	3.125	a (1000)	- [3]
	[Zn(L4)(OAc)Dy(NO ₃) ₂]	MFF-9 (Dy1) CSAPR-9 (Dy2)	2.274 2.219	41 (1000)	b [4]
	[Zn(L4)(9-An)Dy(NO ₃) ₂] <cdot;ch<sub>3CN</cdot;ch<sub>	MFF-9	1.668	a 32.1 (1000)	b [4]
	[ZnDy(NO ₃) ₂ (L5) ₂ (OAc)]	CSAPR-9	2.020	119 (3500)	- [5]
	[ZnDy(L6)(DBM) ₃]	TTD-8	2.670	a 36.5 (2000)	- [6]
	[R,R-Zn L7 Dy(OAc)(NO ₃) ₂]	CSAPR-9	4.762 (Dy1) 5.179 (Dy2)	19.40, 51.82 (1500)	- [7]
	[S,S-Zn L7 Dy(OAc)(NO ₃) ₂]	CSAPR-9	4.749 (Dy1) 5.171 (Dy2)	20.48, 51.72 (1500)	- [7]
	[ZnDy(NO ₃) ₂ (mpko) ₃ (mpkoH)]	CSAPR-9	2.348	a 33.3(1000)	- [8]
	[ZnDy(H ₂ O)(phen)(mb) ₅]	TDD-8	2.29	a 10 (1500)	- [9]
	[(L8 ZnBrDy(ovan)(NO ₃)(H ₂ O)][H ₂ O] ^{0.5} (MeOH)]	MFF-9	0.992	119 211 (1000)	c [10]
	[L8 ZnClDy(thd) ₂]	BTPR-8	1.907	99.7 160 (1000)	c [10]
	[Zn(μ - L) $(\mu$ -OAc)Dy(NO ₃) ₂] <cdot;ch<sub>3CN</cdot;ch<sub>	CSAPR-9	1.18	a 41.55 (1000)	- [11]
ZnDyZn	[ZnLn(L9H4) ₂](NO ₃) ₃ <cdot;6h<sub>2O</cdot;6h<sub>	SAPR-8	0.619	272	c [12]
	[Zn(μ - L6) $(\mu$ -OAc)Ln(NO ₃) ₂]	CSAPR-9 MFF-9	2.196 (Dy1) 2.640 (Dy2)	27.5 (1000)	- [13]
	[Dy{Zn(L2)(OAc)} ₂]BPh ₄ <cdot;ch<sub>3CN</cdot;ch<sub>	JSPC-10	1.467	6.4, 22.4 (1000)	- [14]
	[Zn ₂ Dy(L10) ₂ (MeOH)]NO ₃ <cdot;3meoh<sup>·H₂O</cdot;3meoh<sup>	PBPY-7	0.610	439	11(0.02) [15]
	[Zn ₂ Dy(L10) ₂]NO ₃ <cdot;h<sub>2O</cdot;h<sub>	OC-6	1.879	64 (1200)	2 (0.002) [15]
	[Zn ₂ Dy(L) ₂ Cl ₂][ZnCl ₃ (CH ₃ OH)] <cdot;3ch<sub>3OH</cdot;3ch<sub>	SAPR-8	0.927	140 148 (1000)	c [16]
	[Dy(Zn L11) ₂ (OAc)Cl ₂] <cdot;ch<sub>2Cl₂</cdot;ch<sub>	TDD-8	2.699	a 19 (700)	- [17]
	[ZnCl(μ - L)Dy(μ-L)ClZn]PF₆	SAPR-8	0.547	268 319 (1000)	c [18]
	[(L11 Zn(H ₂ O)) ₂ Dy(H ₂ O)][CF ₃ SO ₃) ₃	MFF-9	2.582 (Dy1) 2.383 (Dy2)	139 185 (1000)	c [19]
	[(L11 ZnBr) ₂ Dy(H ₂ O)][ClO ₄])	TCTPR-9	1.895 (Dy1) 2.068 (Dy2)	211 309 (1000)	c [19]
	[(L11 ZnCl) ₂ Dy(H ₂ O)][ClO ₄] [·] 1.25MeOH	TCTPR-9	1.716 (Dy1) 1.996 (Dy2)	210 291 (1000)	c [19]
	[Zn ₂ Dy(L12H3) ₄] <cdot;3no<sub>3<cdot;2meoh<sup>·1.5H₂O</cdot;2meoh<sup></cdot;3no<sub>	SAPR-8	0.917	a 67 (1000)	c [20]
	{[Dy[Zn(L13)Cl] ₂ (DMF) ₂] [·] Cl}	SAPR-8	5.663	a (2000)	- [21]
	[(L14 ZnBr) ₂ Dy(MeOH) ₂][ClO ₄])	TDD-8	1.060	63.7 95.5 (1000)	c [10]

	[Zn ₂ (L15) ₂ DyCl ₃]·2H ₂ O	MFF-9	3.321	430 ^d 481 (1000) ^d	8	[22]
	[Zn ₂ (L15) ₂ Dy(MeOH)Br ₃]·3H ₂ O	MFF-9	2.635	233	6	[22]
	[Zn ₂ (L15) ₂ Dy(H ₂ O)Br ₂]·[ZnBr ₄] _{0.5}	CSAPR-9	2.115	121	4	[22]
	[Zn ₂ (L16) ₂ DyCl ₃]·2H ₂ O	MFF-9	3.280	398 ^d	8	[22]
>Zn	[Zn ₃ Dy(L17)(NO ₃) ₃ (MeOH) ₃]·4H ₂ O	HH-9	3.726	^a 25.8 (1500)	-	[23]
	[DyZn ₆ (μ ₃ -OH)(Gly) ₆ (μ ₂ -NO ₃) ₃](OH)(NO ₃) ₂ ·8H ₂ O	TCTPR-9	0.205	^a 37.04 (5000)	-	[24]

^a Maxima of the out-of-phase component of ac susceptibility is beyond the window of measurement.

^b The T_B is below the limit of the measurement (2 K).

^c Hysteresis loops are observed at 2 K but are not measured at higher temperatures.

^d Values obtained taking into account the simultaneous presence of Orbach and Raman relaxation processes.

Summary of the ligands:

H₂L1: a Schiff-base ligand formed by a condensation reaction of o-vaniline and 2,2-dimethylpropanediamine in a 2:1 ratio. Hsal: salicylaldehyde.

H₂L2: N,N'-bis(3-methoxysalicylidene)-1,2-diaminoethane.

H₂L3: N,N'-bis(3-methoxysalicylidene)-1,2-cyclohexanediamine.

H₂L4: N,N',N"-trimethyl-N,N"-bis(2-hydroxy-3-methoxy-5-methylbenzyl)diethylene-triamine. H-9-An: 9-anthracene carboxylic acid.

HL5: 2-methoxy-6-[(E)-phenyliminomethyl]phenol.

H₂L6: N,N'-dimethyl-N,N'-bis(2-hydroxy-3-methoxy-5-methylbenzyl)-ethylendiamine
HDBM: 1,3-diphenyl-propane-1,3-dione

H₂L7: phenol,2,2'[2,2-diphenyl-1,2-ethanediyl]bis[(E)-nitrilomethylidyne]-bis(6-methoxy).

mpkoH: methyl 2-pyridyl ketone oxime.

mb: m-methylbenzoate, phen: 1,10-phenanthroline.

H₂L8: N,N'-2,2-dimethylpropylenedi(3-methoxysalicylideneiminato). Ovan: ovanillin.
Thd: 2,2,6,6-tetramethyl-3,5-heptanedionato.

H₅L9: bi-compartmental ligand obtained by reaction of 2-formyl-6-hydroxymethyl-p-cresol with 1,3-diamino-2-propanol.

H₃L10: 2,2',2''-(((nitrilotris(ethane-2,1-diyl))tris(azanediyl))tris(methylene))tris-(4-bromophenol).

H₂L11: N,N'-2,2-dimethylpropylenedi(3-methoxysalicylideneiminato).

H₄L12: [2-(2-hydroxy-3-(hydroxymethyl)-5-methylbenzylideneamino)-2-methyl-propane-1,3-diol].

H₂L13: N,N'-bis(3-methoxysalicylidene)benzene-1,2-diamine.

H₂L14: 2-{(E)-[(3-{[(2E,3E)-3-(hydroxyimino)butan-2-ylidene]amino}-2,2-dimethylpropyl)imino]methyl}-6-methoxyphenol.

H₂L15: N,N'-bis(3-methoxysalicylidene)phenylene-1,2-diamine.

H₂L16: N,N'-bis(3-methoxysalicylidene)-1,2-diaminocyclohexane.

H₆L17: macrocyclic ligand.

Gly = glycine

References

- ¹ A. Watanabe, A. Yamashita, M. Nakano, T. Yamamura and T. Kajiwara, *Chem. Eur. J.*, 2011, **17**, 7428-7432.
- ² J. Long, R. Vallat, R. A. S. Ferreira, L. D. Carlos, F. A. A. Paz, Y. Guari and J. Larionova, *Chem. Commun.*, 2012, **48**, 9974-9976.
- ³ P. Zhang, L. Zhang, S.-Y. Lin and J. Tang, *Inorg. Chem.*, 2013, **52**, 6595-6602.
- ⁴ M. A. Palacios, S. Titos-Padilla, J. Ruiz, J. M. Herrera, S. J. A. Pope, E. K. Brechin and E. Colacio, *Inorg. Chem.*, 2014, **53**, 1465-1474.
- ⁵ A. Upadhyay, S. K. Singh, C. Das, R. Mondol, S. K. Langley, K. S. Murray, G. Rajaraman and M. Shanmugam, *Chem. Commun.*, 2014, **50**, 8838-8841.
- ⁶ Q.-W. Xie, S.-Q. Wu, W.-B Shi, C.-M. Liu, A.-L. Cui and H.-Z. Kou, *Dalton Trans.*, 2014, **43**, 11309-11316.
- ⁷ J. Long, J. Rouquette, J.-M. Thibaud, R. A. S. Ferreira, L. D. Carlos, B. Donnadieu, V. Vieru, L. F. Chibotaru, L. Konczewics, J. Haines, Y. Guari and J. Larionova, *Angew. Chem. Int. Ed.*, 2015, **54**, 2236-2240.
- ⁸ N. C. Anastasiadis, C. D. Polyzou, G. E. Kostakis, V. Bekiari, Y. Lan, S. P. Perlepes, K. F. Konidaris and A. K. Powell, *Dalton Trans.*, 2015, **44**, 19791-19795.
- ⁹ Y. Li, C. Zhang, J.-W. Yu, E.-C. Yang and X.-J. Zhao, *Inorg. Chim. Acta*, 2016, **445**, 110-116.
- ¹⁰ J. P. Costes, S. Titos-Padilla, I. Oyarzabal, T. Gupta, C. Duhayon, G. Rajaraman and E. Colacio, *Inorg. Chem.*, 2016, **55**, 4428-4440.
- ¹¹ I. Oyarzabal, B. Artetxe, A. Rodríguez-Diéz, J. A. García, J. M. Seco and E. Colacio, *Dalton Trans.*, 2016, **45**, 9712-9726.
- ¹² A. Amjad, A. M. Madalan, M. Andruh, A. Caneschi and L. Sorace, *Chem. Eur. J.*, 2016, **22**, 12849-12858.
- ¹³ A. Zabala, J. Cepeda, I. Oyarzabal, A. Rodriguez-Dieguez, J. A. Garcia, J. M. Seco and E. Colacio, *CrystEngComm*, 2017, **19**, 256-264..
- ¹⁴ M. Maeda, S. Hino, K. Yamashita, Y. Kataoka, M. Nakano, T. Yamamura and T. Kajiwara, *Dalton Trans.*, 2012, **41**, 13640-13648.
- ¹⁵ J.-L. Liu, Y.-C. Chen, Y.-Z. Zheng, W.-Q. Lin, L. Ungur, W. Wernsdorfer, L. F. Chibotaru and M.-L. Tong, *Chem. Sci.*, 2013, **4**, 3310-3316.
- ¹⁶ I. Oyarzabal, J. Ruiz, J. M. Seco, M. Evangelisti, A. Camón, E. Ruiz, D. Aravena and E. Colacio, *Chem. Eur. J.*, 2014, **20**, 14262-14269.
- ¹⁷ P.-Y. Shan, H.-F. Li, P. Chen, Y.-M. Tian, W.-B. Sun and P.-F. Yan, *Z. Anorg. Allg. Chem.*, 2015, **641**, 1119-1124.
- ¹⁸ I. Oyarzabal, J. Ruiz, E. Ruiz, D. Aravena, J. M. Seco and E. Colacio, *Chem.*

Commun., 2015, **51**, 12353-12356.

¹⁹ J. P. Costes, S. Titos-Padilla, I. Oyarzabal, T. Gupta, C. Duhayon, G. Rajaraman and E. Colacio, *Chem. Eur. J.*, 2014, **20**, 14262-14269.

²⁰ S. Das, K. S. Bejoymohandas, A. Dey, S. Biswas, M. L. P. Reddy, R. Morales, E. Ruiz, S. Titos-Padilla, E. Colacio and V. Chandrasekhar, *Chem. Eur. J.*, 2015, **21**, 6449-6464.

²¹ Q. Ma, S. Zeng, X. Feng, W. Cao, H. Wang, J. Dou and J. Jiang, *Eur. J. Inorg. Chem.*, 2016, 4194-4198.

²² W.-B. Sun, P.-F. Yan, S.-D. Jiang, B.-W. Wang, Y.-Q. Zhang, H.-F. Li, P. Chen, Z.-M. Wang, S. Gao, *Chem. Sci.*, 2016, **7**, 684-691.

²³ H. L. C. Feltham, Y. Lan, F. Klöwer, L. Ungur, L. F. Chibotaru, A. K. Powell, S. Brooker, *Chem. Eur. J.*, 2011, **17**, 4362-4365.

²⁴ G. Xiong, X.-Y. Qin, P.-F. Shi, Y.-L. Hou, J.-Z. Cui, B. Zhao, *Chem. Commun.*, 2014, **50**, 4255-4257.